Features
- Usable Past 80 GHz
- Low Series Resistance
- Low Capacitance
- High Cutoff Frequency
- Silicon Nitride Passivation
- Polyimide Scratch Protection
- Lead Free (RoHS Compliant)
- Designed for Easy Circuit Insertion
- Available in Pocket Tape and Reel
- Can be Mounted with Solder or Conductive Epoxy

Description and Applications
The MADS-001317-1500 single is a gallium arsenide flip chip Schottky barrier diode. This device is fabricated on OMCVD epitaxial material using a process designed for high device uniformity and extremely low parasitics. This diode is fully passivated with silicon nitride and has an additional layer of polyimide for scratch protection. The protective coating prevents damage to the junction during automated or manual handling. The flip chip configuration is suitable for pick and place insertion. This device with can be attached with solder or conductive epoxy. The high cutoff frequency of this diode allows use through millimeter wave frequencies. Typical applications include single and double balanced mixers in PCN transceivers and radios, police radar detectors, and automotive radar detectors.

Electrical Specifications @ + 25 °C

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Test Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Junction Capacitance (C_J)</td>
<td>0 V, 1 MHz</td>
<td>pF</td>
<td>—</td>
<td>0.020</td>
<td>—</td>
</tr>
<tr>
<td>Total Capacitance (C_T)</td>
<td>0 V, 1 MHz⁻¹</td>
<td>pF</td>
<td>0.030</td>
<td>0.045</td>
<td>0.060</td>
</tr>
<tr>
<td>Dynamic Resistance (R_D)</td>
<td>9.5 - 10.5 mA</td>
<td>Ohms</td>
<td>—</td>
<td>4</td>
<td>7</td>
</tr>
<tr>
<td>Forward Voltage (V_F)</td>
<td>1 mA</td>
<td>Volts</td>
<td>0.60</td>
<td>0.70</td>
<td>0.80</td>
</tr>
<tr>
<td>Reverse Breakdown Voltage (V_BR)</td>
<td>-10 μA</td>
<td>Volts</td>
<td>4.5</td>
<td>7</td>
<td>—</td>
</tr>
</tbody>
</table>

1. Total capacitance is equivalent to the sum of junction capacitance C_J and parasitic capacitance C_P.
Solderable GaAs Flip Chip Schottky Diode

**Absolute Maximum Ratings**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Incident LO Power</td>
<td>+20 dBm</td>
</tr>
<tr>
<td>Incident RF Power</td>
<td>+20 dBm</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-65°C to +125°C</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-65°C to +150°C</td>
</tr>
<tr>
<td>Electrostatic Discharge</td>
<td>Class 0, HBM</td>
</tr>
</tbody>
</table>

2. Operation of this device above any one of these parameters may cause permanent damage.

**Handling Procedures**

The following precautions should be observed to avoid damaging these chips:

**Cleanliness:** The chips should be handled in a clean environment. Do not attempt to clean die after installation.

**Static Sensitivity:** Schottky barrier diodes are ESD sensitive and can be damaged by static electricity. Proper ESD techniques should be used when handling these devices.

**General Handling:** The protective polymer coating on the active areas of these die provides scratch protection, particularly for the metal air bridge which contacts the anode. Die can be handled with tweezers or vacuum pickups and are suitable for use with automatic pick-and-place equipment.

**Mounting Techniques**

Die attach for these devices is made simple through the use of surface mount die attach technology. This chip was designed to be inserted onto hard or soft substrates with the junction side down. This chip can be mounted with conductive epoxy or with solder.

**Solder Die Attach:**

This device can be mounted with Sn63/Pb37 or RoHS compliant solder. Typical reflow profiles are provided on MACOM application note M538 “Surface Mounting Instructions” which can be found on the MACOM website.

**Epoxy Die Attach:**

This device can also be attached with conductive epoxy. The assembly can be preheated to 125 - 150°C. Use a minimum amount of epoxy. Cure epoxy as per manufacturer’s instructions.
1. Pad finish is .2 microns of gold over 4 microns of nickel.
Solderable GaAs Flip Chip Schottky Diode

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